## NSN 5961-01-166-5999

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View Online at https://aerobasegroup.com/nsn/5961-01-166-5999 **Inclosure Material:** Metal **Overall Length:** 1.141 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches Thready Qty Per Inch (tpi): **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 forward gate to source voltage **Current Rating Per Characteristic:** 3.00 amperes forward current, total rms of standard range **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpnp **Thread Series Designator: Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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